TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCXHR162245FT

Low-Voltage 16-Bit Bus Transceiver with Bushold

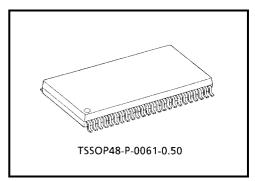
The TC74VCXHR162245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable (\overline{OE}) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The \overline{OE} inputs can be used to disable the device so that the busses are effectively isolated.

The $26 \cdot \Omega$ series resistor helps reducing output overshoot and undershoot without external resistor.

The A, B data inputs include active bushold circuitry,

eliminating the need for external pull-up resisisors to hold unused or floating data inputs at a valid logic level. All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

Features

- 26-Ω series resistors on all outputs
- Low-voltage operation: VCC = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation: $t_{pd} = 3.4 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$

 $t_{pd} = 4.3 \text{ ns (max) (VCC} = 2.3 \text{ to } 2.7 \text{ V)}$

 $: t_{pd} = 5.7 \text{ ns (max) (VCC} = 1.8 \text{ V)}$

- 3.6-V tolerant control inputs.
- Output current: $IOH/IOL = \pm 12 \text{ mA (min)} (VCC = 3.0 \text{ V})$

 $: I_{OH}/I_{OL} = \pm 8 \text{ mA (min) (V}_{CC} = 2.3 \text{ V)}$

: $I_{OH}/I_{OL} = \pm 4 \text{ mA (min) (V}_{CC} = 1.8 \text{ V)}$

- Latch-up performance: ±300 mA
- ESD performance: Machine model > ±200 V

: Human body model > $\pm 2000 \text{ V}$

Package: TSSOP (thin shrink small outline package)

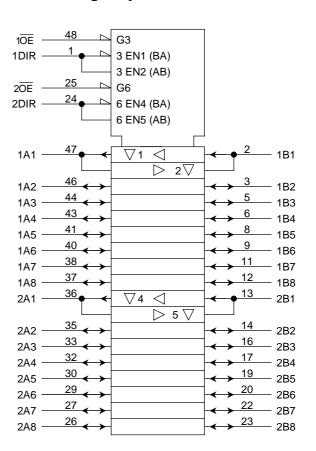
Note 1: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

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Pin Assignment (top view)

10E 1DIR 48 1B1 2 47 1A1 1B2 3 1A2 46 GND 4 **GND** 45 5 1B3 1A3 1B4 6 43 1A4 7 V_{CC} 42 V_{CC} 1B5 8 1A5 1B6 9 40 1A6 GND 10 **GND** 39 1B7 11 38 1A7 1B8 12 37 1A8 2B1 13 36 2A1 2B2 14 35 2A2 GND 15 GND 34 2B3 16 33 2A3 2B4 17 32 2A4 V_{CC} 18 31 Vcc 2B5 19 30 2A5 2B6 20 29 2A6 GND 21 **GND** 2B7 22 2A7 2B8 23 26 2A8 2DIR 24 2OE 25

IEC Logic Symbol



Truth Table

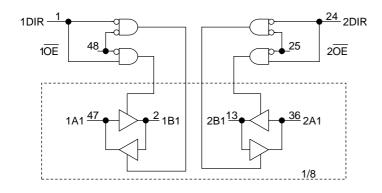
Inp	uts	Function		
1OE	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs
L	L	Output	Input	A = B
L	Н	Input	Output	B=A
Н	Х	Z		Z

Inp	uts	Fun		
2 OE	2DIR	BUS 2A1-2A8	BUS 2B1-2B8	Outputs
L	L	Output	Input	A = B
L	Н	Input	Output	B=A
Н	Х	Z		Z

X: Don't care

Z: High impedance

System Diagram





Maximum Ratings

Characteristics		Symbol	Rating	Unit	
Power supply voltage		V _{CC}	-0.5 to 4.6	V	
	(DIR, $\overline{\text{OE}}$)		-0.5 to 4.6		
DC input voltage	(An, Bn)	V_{IN}	-0.5 to $V_{CC}+0.5$	V	
	(All, Dil)		(Note 2)		
DC output voltage	(An, Bn)	Vout	-0.5 to V_{CC} + 0.5	V	
DC output voltage	(An, Bn)		(Note 3)		
Input diode current		I _{IK}	-50	mA	
Output diode current		lok	±50 (Note 4)	mA	
Output current		lout	±50	mA	
Power dissipation		P_{D}	400	mW	
DC V _{CC} /ground current per supply pin		I _{CC} /I _{GND}	±100	mA	
Storage temperature		T _{stg}	-65 to 150	°C	

Note 2: OFF state

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Range (Note 5)

Characteristics		Symbol	Rating	Unit	
Power supply voltage	nnly voltoge		1.8 to 3.6	V	
Tower supply voltage		V _{CC}	1.2 to 3.6 (Note 6)	V	
Input voltage	(DIR, \overline{OE})	V _{IN}	-0.3 to 3.6	V	
input voitage	Input voltage (An, Bn)		0 to V _{CC} (Note 7)	V	
Output voltage	(An, Bn)	V _{OUT}	0 to V _{CC} (Note 8)	V	
			±12 (Note 9)		
Output current		I _{OH} /I _{OL}	±8 (Note 10)	mA	
			±4 (Note 11)		
Operating temperature		T _{opr}	-40 to 85	°C	
Input rise and fall time		dt/dv	0 to 10 (Note 12)	ns/V	

Note 5: Floating or unused control inputs must be held high or low.

Note 6: Data retention only

Note 7: OFF state

Note 8: High or low state

Note 9: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 10: $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$

Note 11: $V_{CC} = 1.8 \text{ V}$

Note 12: $V_{\mbox{\footnotesize{IN}}} = 0.8$ to 2.0 V, $V_{\mbox{\footnotesize{CC}}} = 3.0$ V



Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < V_{CC} ≤ 3.6 V)

Characteristics		Symbol	Test Co	ondition		Min	Max	Unit		
Onaracteris	itios	Cymbol			Tool Containen		V _{CC} (V)	IVIIII	IVIAX	Offic
Input voltage	H-level	V_{IH}	_	_	2.7 to 3.6	2.0		V		
input voitage	L-level	V _{IL}	_	_	2.7 to 3.6	_	0.8	V		
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2				
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -6 mA	2.7	2.2	_			
				$I_{OH} = -8 \text{ mA}$	3.0	2.4				
Output voltage				$I_{OH} = -12 \text{ mA}$	3.0	2.2		V		
				$I_{OL} = 100 \mu A$	2.7 to 3.6	_	0.2			
	L-level	V _{OL}	V _{OL}	V_{OL}	\/ \/ an\/	I _{OL} = 6 mA	2.7	_	0.4	
	L-level				VOL	VOL	VOL	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 8 mA	3.0
				I _{OL} = 12 mA	3.0		0.8			
Input leakage currer (DIR, $\overline{\text{OE}}$)	t	I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7 to 3.6	_	±5.0	μА		
Bushold input minim	um drive		V _{IN} = 0.8 V		3.0	75	_	^		
hold current		I _I (HOLD)	V _{IN} = 2.0 V		3.0	-75		μА		
Bushold input over-o	Irive current	ve current , (Note 13)		3.6	_	450	^			
to change state		I _{I (OD)}	(Note 14		3.6	_	-450	μА		
3-state output OFF state current I _C		1	V _{IN} = V _{IH} or V _{IL}		2.7 to 3.6		±10.0	^		
3-state output OFF s	state Currefit	l _{OZ}	$V_{OUT} = V_{CC}$ or GND		2.7 10 3.0	_	£10.0	μА		
Quiescent supply cu	rrent	Icc	$V_{IN} = V_{CC}$ or GND		2.7 to 3.6	_	20.0	μА		
Increase in I _{CC} per i	nput	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	750	μΑ		

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

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DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteris	stics	Symbol	Test C	ondition	V _{CC} (V)	Min	Max	Unit		
	H-level	V _{IH}		_	2.3 to 2.7	1.6	_	.,		
Input voltage	L-level	VIL	-	_	2.3 to 2.7	_	0.7	V		
				I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2				
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -4 mA	2.3	2.0				
				I _{OH} = -6 mA	2.3	1.8	_			
Output voltage				$I_{OH} = -8 \text{ mA}$	2.3	1.7	_	V		
				I _{OL} = 100 μA	2.3 to 2.7	_	0.2			
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH}$ or V_{IL} $I_{OL} = 6 \text{ mA}$	I _{OL} = 6 mA	2.3	_	0.4	
				I _{OL} = 8 mA	2.3	_	0.6			
Input leakage currer (DIR, $\overline{\text{OE}}$)	nt	I _{IN}	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μА		
Bushold input minim	num drive	1	V _{IN} = 0.7 V		2.3	45	_			
hold current	V _{IN} = 1.6 V			2.3	-45	_	μА			
Bushold input over-o	Bushold input over-drive current			(Note 13)	2.7	_	300	μА		
to change state		lı (OD)		(Note 14)	2.7	_	-300	μΑ		
3-state output OFF	state current	l _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		2.3 to 2.7	_	±10.0	μА		
Quiescent supply cu	ırrent	Icc	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	μΑ		

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

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DC Characteristics (Ta = -40 to 85° C, $1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$)

Characteri	stics	Symbol	Test C	ondition	V _{CC} (V)	Min	Max	Unit		
Input voltage	H-level	V _{IH}	-	_	1.8 to 2.3	0.7 × V _{CC}		V		
input voltage	L-level	V _{IL}	-	_	1.8 to 2.3		0.2 × V _{CC}	V		
	H-level	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OH} = -100 μA	1.8	V _{CC} - 0.2				
Output voltage				$I_{OH} = -4 \text{ mA}$	1.8	1.4	_	V		
	L-level	VoL	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	\\\\\r\\	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100 μA	1.8	_	0.2	
	L-level	VOL	VIN - VIH OI VIL	I _{OL} = 4 mA	1.8		0.3	3		
Input leakage currer (DIR, $\overline{\text{OE}}$)	nt	I _{IN}	V _{IN} = 0 to 3.6 V		1.8		±5.0	μА		
Bushold input minin	num drive	li mai si	V _{IN} = 0.36 V		1.8	25	_	^		
hold current		I (HOLD)	V _{IN} = 1.26 V		1.8	-25	_	μА		
Bushold input over-	drive current	1		(Note 13)		_	200	^		
to change state		I _I (OD)	(Note 14)		1.8	_	-200	μА		
3-state output OFF	state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		1.8	_	±10.0	μА		
Quiescent supply cu	urrent	I _{CC}	$V_{IN} = V_{CC}$ or GND		1.8	_	20.0	μΑ		

Note 13: An external driver must source at least the specified current to switch from LOW-to-HIGH.

Note 14: An external driver must sink at least the specified current to switch from HIGH-to-LOW.

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ Ω)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
	4		1.8	1.5	5.7	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	1.0	4.3	ns
	t _{pHL}		3.3 ± 0.3	0.8	3.4	
			1.8	1.5	7.6	
3-state output enable time	t _{pZL} t _{pZH}	Figure 1, Figure 3	2.5 ± 0.2	1.0	5.7	ns
			3.3 ± 0.3	0.8	4.2	
			1.8	1.5	5.7	
3-state output disable time	t _{pLZ}	Figure 1, Figure 3	2.5 ± 0.2	1.0	4.8	ns
	t _{pHZ}		3.3 ± 0.3	0.8	4.1	
Output to output skew			1.8	_	0.5	
	tosLH	(Note 15)	2.5 ± 0.2	_	0.5	ns
	t _{osHL}		3.3 ± 0.3	_	0.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 15: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|)$



Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
L		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	1.8	0.15	
Quiet output maximum dynamic V _{OI}	V _{OLP}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	2.5	0.25	V
. 5		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	3.3	0.35	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	1.8	-0.15	
Quiet output minimum dynamic V _{OI}	V _{OLV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	2.5	-0.25	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	3.3	-0.35	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	1.8	1.55	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	2.5	2.05	V
·		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (Note 16)	3.3	2.65	

Note 16: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol Test Condition			Tun	Unit	
Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Uniii
Input capacitance	C _{IN}	_		1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	_		1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	$f_{IN} = 10 \text{ MHz}$ (N	Note 17)	1.8, 2.5, 3.3	20	pF

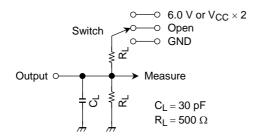
Note 17: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$

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AC Test Circuit



Parameter	Switch		
t _{pLH} , t _{pHL}	Open		
^t pLZ ^{, t} pZL	V _{CC} × 2 @V _C	$_{CC} = 3.3 \pm 0.3 \text{ V}$ $_{CC} = 2.5 \pm 0.2 \text{ V}$ $_{CC} = 1.8 \text{ V}$	
t _{pHZ} , t _{pZH}	GND		

Figure 1

AC Waveform

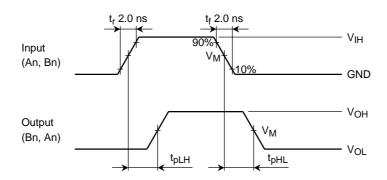
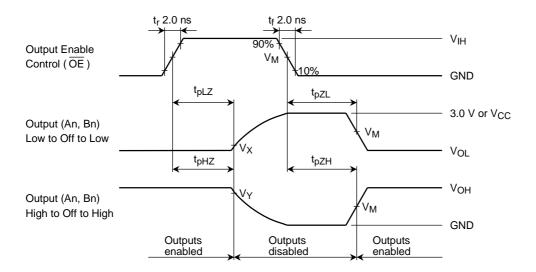


Figure 2 tpLH, tpHL



 $\textbf{Figure 3} \quad t_{\text{pLZ}},\, t_{\text{pHZ}},\, t_{\text{pZL}},\, t_{\text{pZH}}$

Symbol		V _{CC}	
Symbol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2~\textrm{V}$	1.8 V
V _{IH}	2.7 V	V _{CC}	V _{CC}
V_{M}	1.5 V	V _{CC} /2	V _{CC} /2
VX	$V_{OL} + 0.3 V$	V _{OL} + 0.15 V	V _{OL} + 0.15 V
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V

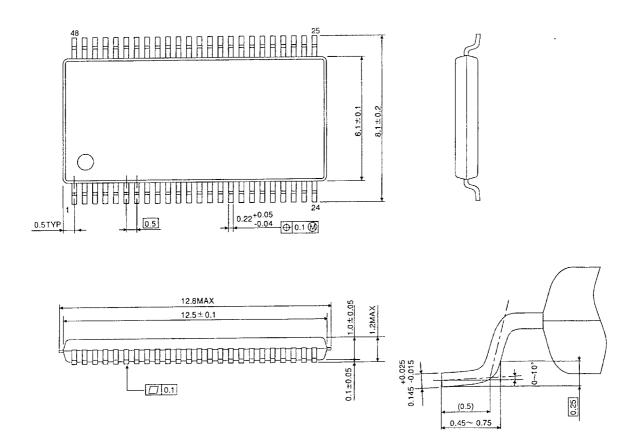
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Unit: mm

Package Dimensions

TSSOP48-P-0061-0.50



Weight: 0.25 g (typ.)

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